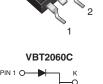


## Vishay General Semiconductor

# **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.40 \text{ V}$  at  $I_F = 5 \text{ A}$ 





HEATSINK

PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	150 A			
V <sub>F</sub> at I <sub>F</sub> = 10 A	0.52 V			
T <sub>J</sub> max.	150 °C			
Diode variations	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation



 Meets MSL level 1, per J-STD-020, LF maximum FREE peak of 245 °C

 Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT2060C	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	20		
	per diode		10	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150	°C	

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage per diode (1)	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.49	-	V
	I <sub>F</sub> = 10 A			0.57	0.65	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.40	-	
	I <sub>F</sub> = 10 A			0.52	0.59	
Reverse current per diode (2)	V - 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	-	850	μA
	V <sub>R</sub> = 60 V	T <sub>A</sub> = 125 °C		14	40	mA

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VBT2060C	UNIT
Typical thormal registance	per diode	$R_{ heta JC}$	3.2	- °C/W
Typical thermal resistance	per device		1.9	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VTB2060C-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VTB2060CM3/8W	1.39	8W	800/reel	Tape and reel	

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

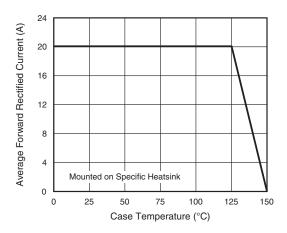


Fig. 1 - Maximum Forward Current Derating Curve

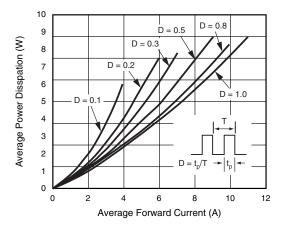


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

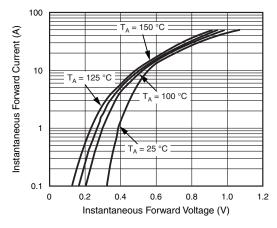


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

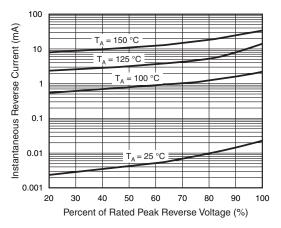


Fig. 4 - Typical Reverse Characteristics Per Diode



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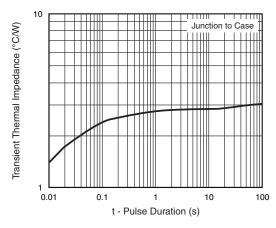


Fig. 5 - Typical Transient Thermal Impedance Per Diode

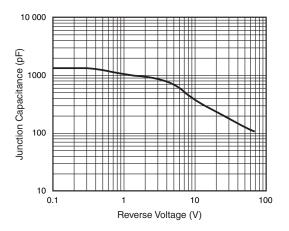
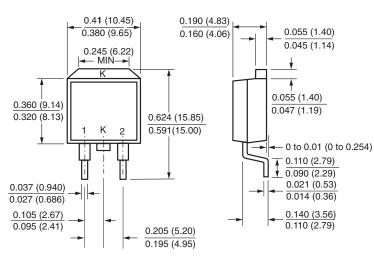


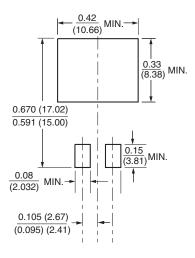
Fig. 6 - Typical Junction Capacitance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### **TO-263AB**



### **Mounting Pad Layout**





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